

BSZ110N06NS3 G Information


For Reference Only

Part Number [BSZ110N06NS3 G](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 60V 20A TSDSON-8
Package 8-PowerVDFN
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


BSZ110N06NS3 G Specifications

Manufacturer Part Number	BSZ110N06NS3 G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	20A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 23µA
Gate Charge (Qg) (Max) @ Vgs	33nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2700pF @ 30V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2.1W (Ta), 50W (Tc)
Rds On (Max) @ Id, Vgs	11 mOhm @ 20A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TSDSON-8
Package / Case	8-PowerVDFN

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BSZ110N06NS3 G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSZ110N06NS3 G Payment Methods



BSZ110N06NS3 G Shipping Methods



If you have any question about BSZ110N06NS3 G, please do not hesitate to contact us!

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